SEMICONDUCTOR

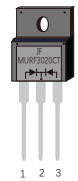
MURF3020CT THRU MURF3060CT

GLASS PASSIVATED SUPER FAST RECTIFIER

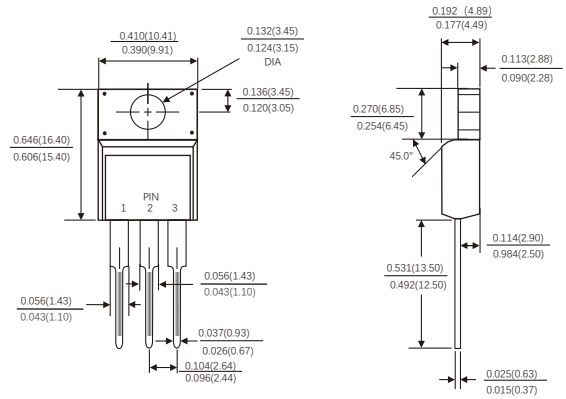
Reverse Voltage - 200 -600 Volts
Forward Current - 30.0Amperes

FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Fast switching for high efficiency
- Low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds, 0.25"(6.35mm)from case
- Component in accordance to RoHS 2015/863/EU



ITO-220AB



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC ITO-220AB molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked
- Mounting Position: Any

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load,derate by 20%.)

Parameter		Symbols	MURF 3020CT	MURF 3040CT	MURF 3060CT	Units
Maximum repetitive peak reverse voltage		V_{RRM}	200	400	600	Volts
Maximum RMS voltage		V_{RMS}	140	280	420	Volts
Maximum DC blocking voltage		V_{DC}	200	400	600	Volts
Maximum average forward rectified current(see Fig.1)	Per leg	$I_{(AV)}$	15.0			Amps
	Total device		30.0			
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)		I_{FSM}	220			Amps
Maximum instantaneous forward voltage at 15.0 A per leg(Note 1)		V_F	1.05	1.30	1.7	Volts
Maximum instantaneous reverse current at rated DC blocking voltage(Note 1)	T_J=25°C	I_R	5			μA
	T_J=125°C		250			
Maximum Reverse Recovery Time (Note 2)		Trr	35			ns
Typical thermal resistance (Note 3)		$R_{\theta JC}$	3.5			°C/W
Operating junction temperature range		T_J	-55 to+150			°C
Storage temperature range		T_{STG}	-55 to+150			°C

Notes: 1. Pulse test: 300us pulse width,1% duty cycle
2. Reverse recovery test conditions I_F=0.5A,I_R=1.0A, Irr=0.25A
3. Thermal resistance from junction to case, Per diode

FIG.1-FORWARD CURRENT DERATING CURVE

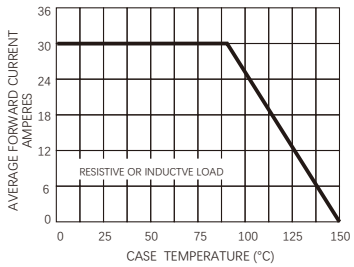


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

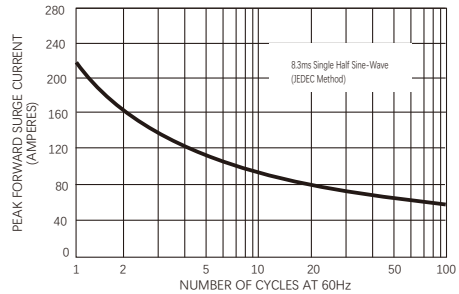


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

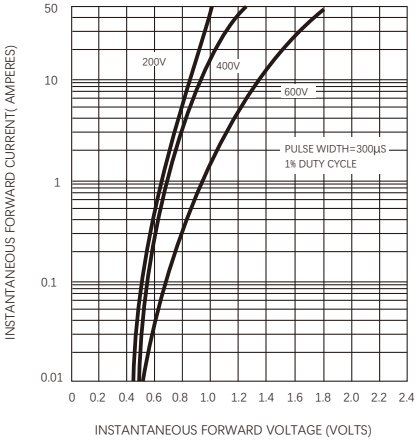
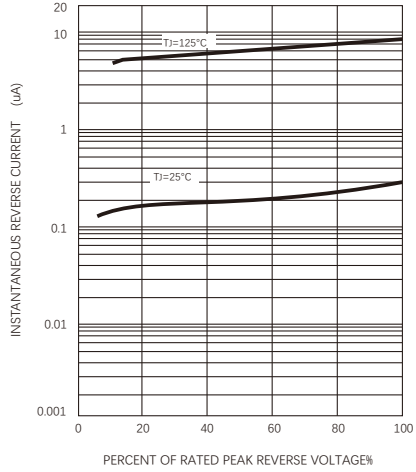


FIG.4-TYPICAL REVERSE CHARACTERISTICS



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